

Digital Driver



Features

Output voltage 8 V_{pp}

High SNR > 25

Flat gain up to 7 GHz

Single voltage power supply

Applications

LiNbO₃ modulators

12.5 Gbps NRZ

OC-192 SONET / SDH

Research & Development

Options

Heat-sink

Alternative RF connectors

High output voltage version (12 V_m)

High bandwidth version (15 GHz)

The DR-DG-10-MO-NRZ is a driver module specially designed for 10 Gbps / 12.5 Gbps data transmission with NRZ format. It exhibits a 20 dB gain and can deliver an output signal up to 8 V_{no} .

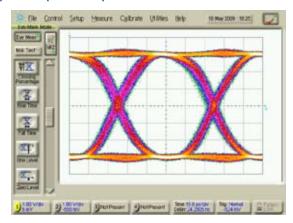
The DR-DG-10-MO-NRZ is a key component to obtain high quality 12.5 Gbps eye diagrams with high SNR, low jitter and short rise and fall time. It operates from a single power supply for safety and ease of use, and offers gain control over 3 dB. It comes with SMA type RF connectors (female in, male out) and with an optional heat sink.

Performance Highlights

Parameter	Min	Тур	Max	Unit
Cut-off frequencies	50 k	-	7 G	Hz
Output voltage	-	6	-	V _{pp}
Gain	-	21	-	dB
Saturated output power	21	-	-	dBm
Added jitter	-	1.1	-	ps
Rise / Fall time	-	22 / 22	-	ps

Measurements for $V_{bias} = 12 \text{ V}$, $V_{amp} = 0.4 \text{ V}$, $I_{bias} = 260 \text{ mA}$

12.5 Gbps Output Response





Digital Driver

DC Electrical Characteristics

Parameter	Symbol	Min	Тур	Max	Unit
Supply voltage (fixed)	V _{bias}	-	12	-	V
Current consumption	l	-	0.260	-	А
Gain control voltage	V _{amp}	0	0.4	-	V

Electrical Characteristics

Conditions: $V_{in} = 0.5 V_{pp}$, $T_{amb} = 25 ^{\circ}C$, 50 Ω system

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Lower frequency	f _{3dB} , lower	-3 dB point	-	-	50	kHz
Upper frequency	f _{3dB} , upper	-3 dB point	6	7	-	GHz
Gain	S ₂₁	Small signal	-	21	-	dB
Gain ripple	-	< 7 GHz	-	±1.5	-	dB
Input return loss	S ₁₁	50 kHz < f < 10 GHz	-	-10	-	dB
Output return loss	S ₂₂	50 kHz < f < 10 GHz	-	-10	-	dB
Saturated output power	P _{sat}	$V_{in} = 0.5 V_{pp}$	21	-	22	dBm
Output voltage	V _{out}	$V_{in} = 0.5 V_{pp}$	4	-	8	V_{pp}
Rise / Fall time	t _r / t _f	20 % - 80 %	-	22 / 22	-	ps
Added jitter	J _{RMS}	$J_{RMS} = \sqrt{J_{RMS-total}^2 - J_{RMS-source}^2}$	-	1.1	-	ps
Power dissipation	Р	$V_{out} = 8 V_{pp}$	-	3.2	-	W

Absolute Maximum Ratings

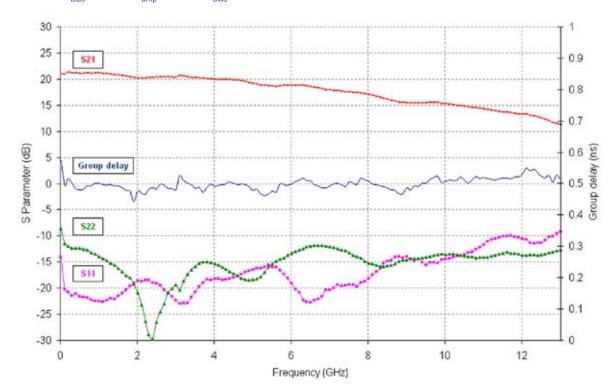
Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input voltage	V _{in}	-	1.5	V _{pp}
Supply voltage	V _{bias}	0	13	V
DC current	bias	0	0.4	А
Gain control voltage	V _{amp}	0	1	V
Power dissipation	P _{diss}	-	5.2	W
Temperature of operation	T _{op}	-5	+50	W
Storage temperature	T _{st}	-40	+70	°C



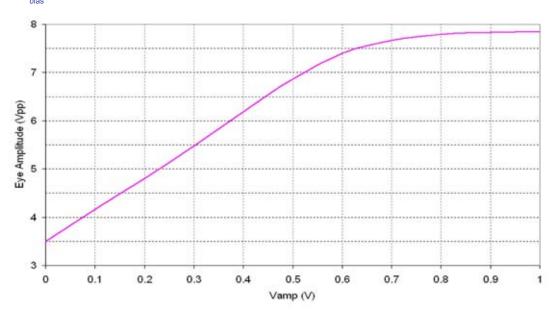
Digital Driver

S Parameters Curves Conditions: V_{bias} = 12 V, V_{amp} = 0.4 V, I_{bias} = 260 mA



Typical Output Voltage Amplitude vs V_{amp}

Conditions: V_{bias} = 12 V



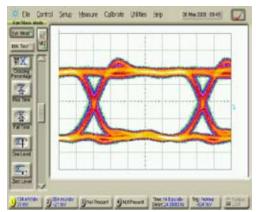


Digital Driver

Eye Diagrams

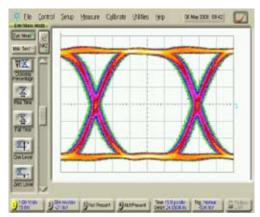
10.709 Gbps data rate

Conditions: Ratio $\frac{1}{2}$, Pattern 2³¹-1 V_{bias} = 12 V, V_{amp} = 0.4 V, I_{bias} = 260 mA



Input signal

Genrated by Anritsu MP1758A Eye amplitude = 0.50 V_{pp} , Rise time = 15.5 psJitter RMS = 1.68 ps, SNR = 16.4 ms

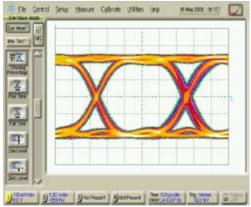


Output response

Measured using Agilent 86100B with two 50 GHz 8348A channels module, and without precision time-base module Eye amplitude = 6.13 V_{pp} , Rise time = 22.6 ps Jitter RMS = 1.95 ps, SNR = 41.6

12.5 Gbps data rate

Conditions: Ratio $\frac{1}{2}$, Pattern 2³¹-1 V_{bias} = 12 V, V_{amo} = 0.4 V, I_{bias} = 260 mA

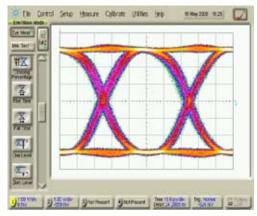


Input signal

Generated with a NEL MOF15A 2:1 selector

Eye amplitude = 0.50 V_{pp} , Rise time = 14.1 ps

Jitter RMS = 2.16 ps, SNR = 11.1



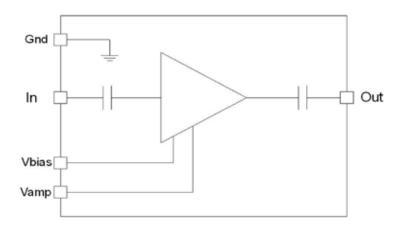
Output response

Measured using Agilent 86100B with two 50 GHz 8348A channels module, and without precision time-base module Eye amplitude = 6.18 V_{pp} , Rise time = 22.9 ps Jitter RMS = 2.44 ps, SNR = 36.9



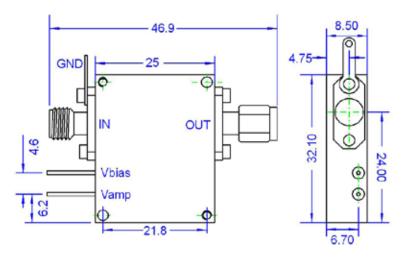
Digital Driver

Electrical Schematic Diagram



Mechanical Diagram and Pinout

All measurements in mm





The heatsinking of the module is necessary. It's user responsability to use an adequate heatsink. Refer to page 6 for Photline Technologies recommended heatsink.

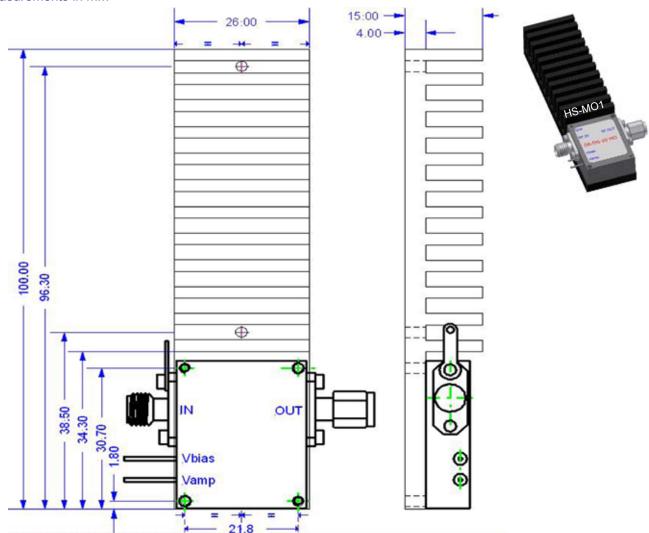
PIN	Function	Operational Notes
IN	RF In	SMA-connector female
OUT	RF Out	SMA-connector male
V _{bias}	Power supply voltage	Set at typical operating specification
V _{amp}	Output voltage amplitude adjustment	Adjust for gain control tuning



Digital Driver

Mechanical Diagram and Pinout with HS-MO1 Heatsink

All measurements in mm



ABOUT US

Photline Technologies is a provider of Fiber Optics Modulation Solutions based on the company LiNb03 modulators and high-speed electronics modules. Photline Technologies offers high speed and high data rate modulation solutions for the telecommunication industry and the defense, aerospace, instruments and sensors markets. The products offered by the company include: comprehensive range of intensity and phase modulators (800 nm, 1060 nm, 1300 nm, 1550 nm), RF drivers and modules, transmitters and modulation units.

Photline Technologies phone: +33 (0) 381 853 180 fax: +33 (0) 381 811 557 16, rue Auguste Jouchoux F-25 000 Besançon Photline Technologies reserves the right to change, at any time and without notice, the specifications, design, function or form of its products described herein. All statements, specification, technical information related to the products herein are given in good faith and based upon information believed to be reliable and accurate at the moment of printing. However the accuracy and completeness thereof is not guaranteed. No liability is assumed for any inaccuracies and as a result of use of the products. The user must validate all parameters for each application before use and he assumes all risks in connection with the use of the products.